



40V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BVDSS	RDS(ON) Max	I _D Tc = +25°С
40V	10mΩ @ V _{GS} = 10V	50A

Description and Applications

This new generation MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

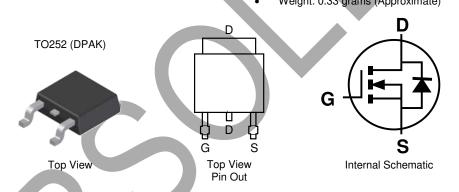
- **DC-DC** converters
- Power management functions
- Analog switches

Features and Benefits

- Rated to +175°C ideal for high ambient temperature environments
- Low On-Resistance
- Low Input Capacitance .
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.
- https://www.diodes.com/guality/product-definitions/
- An Automotive-Compliant Part is Available Under Separate Datasheet (DMNH4011SK3Q)

Mechanical Data

- Package: TO252
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.33 grams (Approximate)



Ordering Information (Note 4)

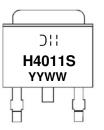
Part Number		Baakaga	Packing			
	Fatt Number	Package	Qty.	Carrier		
	DMNH4011SK3-13	TO252 (DPAK)	2,500	Tape & Reel		
Notes:	Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant, All applicable RoHS exemptions applied.					

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



DII = Manufacturer's Marking H4011S = Product Type Marking Code YYWW = Date Code Marking YY = Last Digit of Year (ex: 14 = 2014) WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			VDSS	40	V
Gate-Source Voltage			Vgss	±20	V
Continuous Drain Current (Note 6)	Steady State	Tc = +25°C T _C = +100°C	lo	50 27	А
Maximum Body Diode Forward Current (Note 6)			ls	120	A
Pulsed Drain Current (380µs Pulse, Duty Cycle = 1%)			ldм	120	Α

Thermal Characteristics

		1
Symbol	Value	Unit
Po	2.6	W
Reja	47	°C/W
PD	50	W
Rejc	3	°C/W
TJ, TSTG	-55 to +175	°C
-	Reja PD Rejc	Pp 2.6 RθJA 47 Pp 50 RθJC 3

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

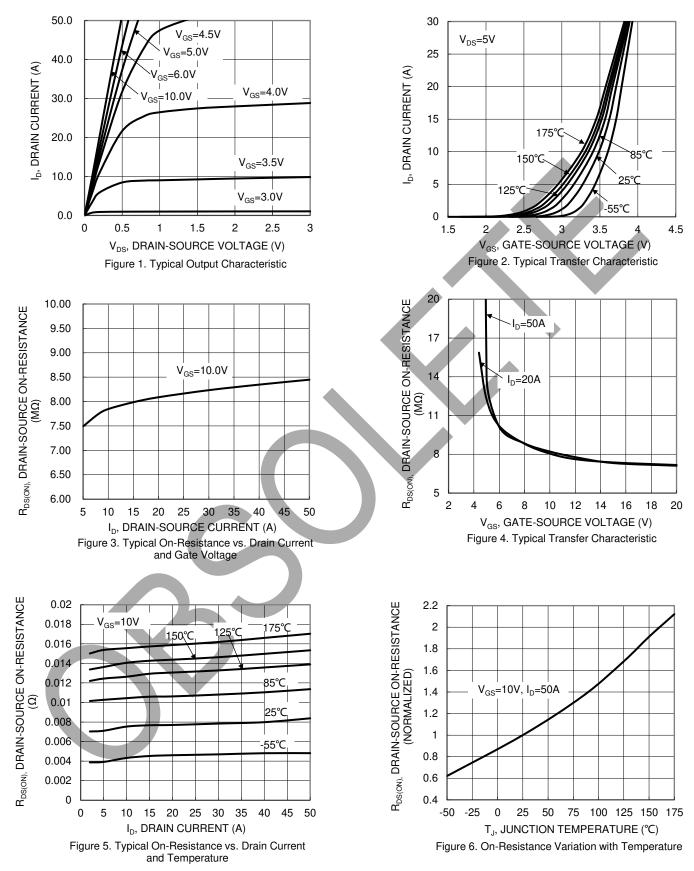
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						•
Drain-Source Breakdown Voltage	BVDSS	40	—		V	V _{GS} = 0V, I _D = 250µA
Zero Gate Voltage Drain Current	IDSS	_	—	1	μA	$V_{DS} = 40V, V_{GS} = 0V$
Gate-Source Leakage	IGSS			±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	VGS(TH)	2		4	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
Static Drain-Source On-Resistance	RDS(ON)	_		10	mΩ	$V_{GS} = 10V, I_{D} = 50A$
Diode Forward Voltage	Vsd	_	0.9	1.2	V	$V_{GS} = 0V, I_{S} = 20A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss		1,405			V _{DS} = 20V, V _{GS} = 0V, f = 1MHz
Output Capacitance	Coss		247	_	pF	
Reverse Transfer Capacitance	Crss	_	108	_		
Gate Resistance	Rg	_	2.2	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge	Qg		25.5	_		
Gate-Source Charge	Q _{gs}	_	4.6	_	nC	V_{DS} = 20V, V_{GS} = 10V , I_{D} = 50A
Gate-Drain Charge	Qgd	_	6.9	_		
Turn-On Delay Time	td(on)	_	4.6	_		
Turn-On Rise Time	t _R		3.7			$\label{eq:VDD} \begin{split} V_{DD} &= 20V, \ V_{GS} = 10V, \\ I_D &= 50A, \ R_G = 3.5\Omega \end{split}$
Turn-Off Delay Time	tD(OFF)	_	16	_	ns	
Turn-Off Fall Time	tF	_	5.1]	
Body Diode Reverse Recovery Time	trr	_	22.1	_	ns	
Body Diode Reverse Recovery Charge	Qrr		13.4		nC	IF = 50A, di/dt = 100A/μs

Notes:

Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
Device mounted on infinite heat sink and measured by thermal couple attached on bottom heat sink of package.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.



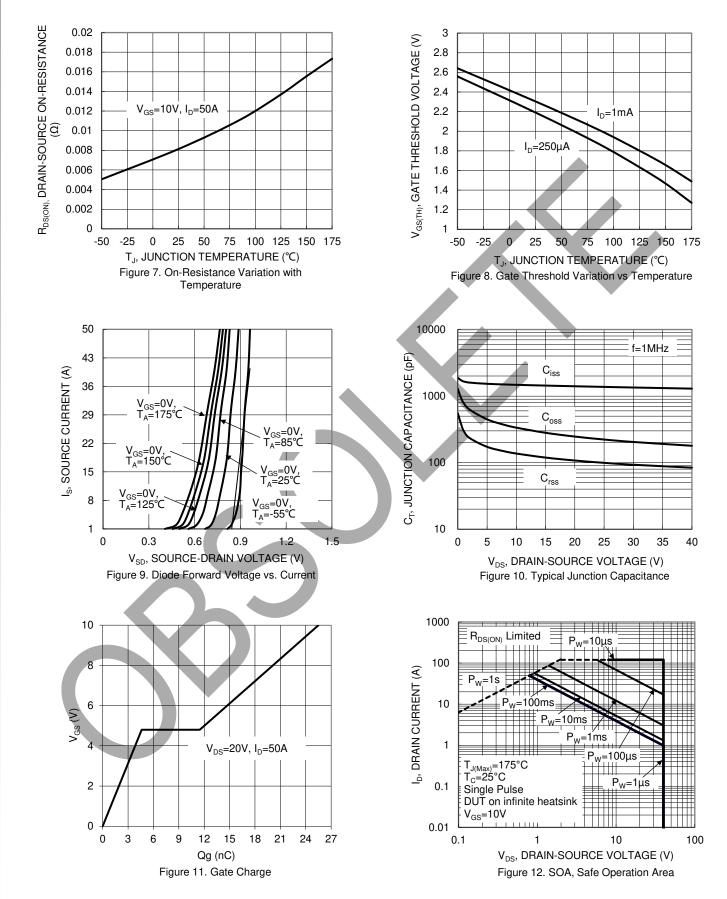
DMNH4011SK3



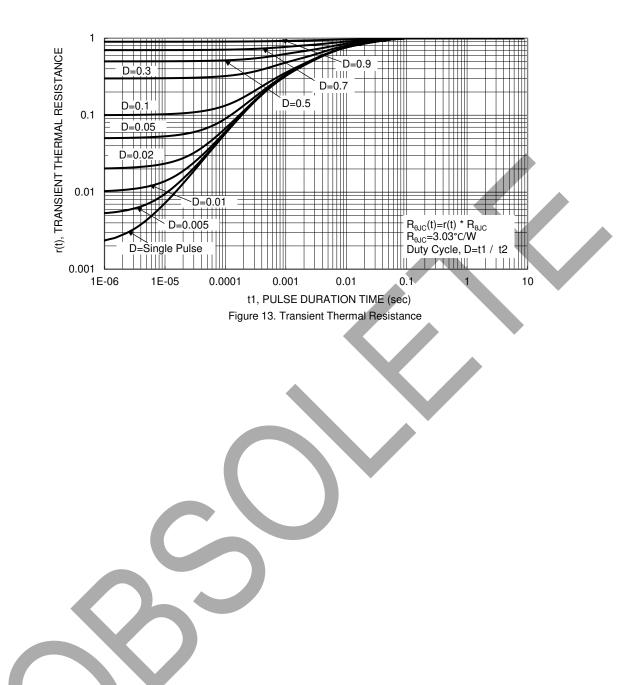
DBSOLETE – PART DISCONTINUED



DMNH4011SK3







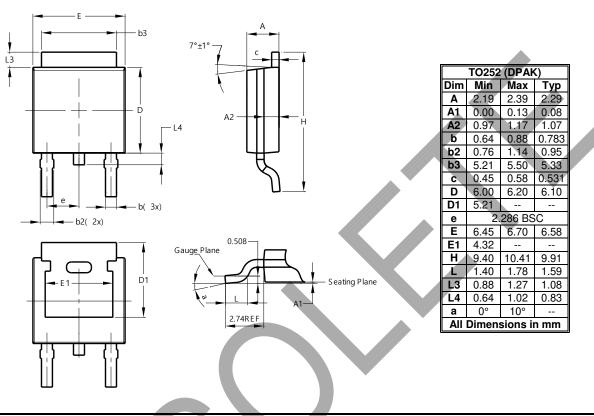


Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

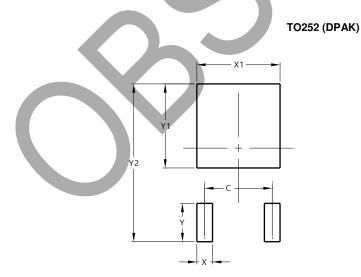






Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	4.572
Х	1.060
X1	5.632
Y	2.600
Y1	5.700
Y2	10.700



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